



# **SPECIFICATION FOR RoHS 6 COMPLIANT SMT TCXO** MtronPTI P/N: M6029S061

## **Electrical Specifications:**

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Frequency	Fo		20.000000		MHz	
Frequency Tolerance		-1.0		+1.0	ppm	Before reflow soldering
		-2.0		+2.0		After 2 reflows, @ +260°C 10 seconds
		Fr	equency Sta	bility		
vs. Stability	ΔF/F	-1.5		+1.5	ppm	Over operating temperature range
vs. Aging		-1.0		+1.0	ppm	per years
Frequency vs. Supply				±0.2	ppm	For 5% supply variation
Frequency vs. Load				±0.2	ppm	For 10% load variation
			RF Output	t		
Output Type		Cli	pped Sine Way	ve		
Output Load		10 kΩ    10 pF				
Output Level	Vout	0.8			V	pk-pk
	S	upply Volt	age & Power	<sup>·</sup> Consump	otion	
Operating Voltage	V <sub>DD</sub>	3.135	3.3	3.465	V	
Operating Current	IDD			3.0	mA	

#### **Environmental Conditions:**

Operating Temperature	TA	-40		+85	°C	
Storage Temperature	Ts	-55		+125	°C	
Shock	Per MIL-	Per MIL-STD-202, Method 213, Condition C (100 g's, 6 <i>msec</i> duration, ½ sinewave)				
Vibration	Per MIL-STD-202, Method 201 & 204 (10 g's from 10-2000Hz)					
Hermeticity	Per MIL-STD-202, Method 112 (1 x 10 <sup>-8</sup> atm cc/s of Helium) (Crystal Only)					
Solderability	Per EIAJ-STD-002					
Package Type	5.0 x 7.0 x 2.0 mm, 4-pad Ceramic Leadless Chip Carrier					





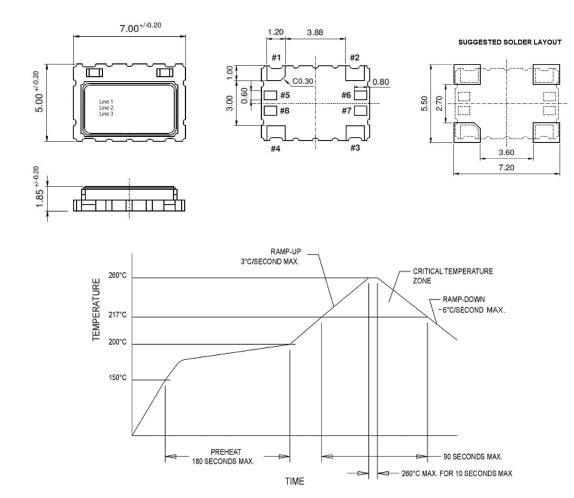
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## **Dimensions, Marking and Pin-Out Information:**

Part Marking			
Line 1	TBD		
Line 2	20M0000		
Line 3	М ууwwvv		

Legend			
*	Pad 1 Indicator		
уу	Year		
ww	Work week		
vv	Factory code		

Pad	Function	
1	N/C	
2	Ground	
3	Output	
4	+V <sub>DD</sub>	
5-8	Do Not Connect	





#### **Data Sheet Revision Table**

Date	Rev.	Orig.	Details of Revision
07/29/16	0	MM	Original release.